



60V NPN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

### Features

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 5A High Continuous Current
- R<sub>SAT</sub> = 30mΩ for a Low Equivalent On-Resistance
- Low Saturation Voltage V<sub>CE(SAT)</sub> < 65mV @ I<sub>C</sub> = 1A
- h<sub>FE</sub> Specified Up to 10A for High Current Gain Hold Up
- Complementary PNP Type: ZXTP2012Z
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208(2)
- Weight: 0.05 grams (Approximate)

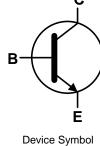
### Application

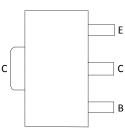
- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Backlight Inverters
- Power Switches
- Gate Driving MOSFETs and IGBTs

SOT89



Top View





Top View Pin Out

### Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTN2010ZTA	AEC-Q101	851	7	12	1,000
ZXTN2010Z-13R	AEC-Q101	851	13	12	4,000
ZXTN2010ZQTA	Automotive	851	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

6. Halogen- and Antimony-free Green products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



851 = Product Type Marking Code



## **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Base Current	Ι <sub>Β</sub>	2	A
Continuous Collector Current	lc	5	A
Peak Pulse Current	I <sub>CM</sub>	20	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Linear Derating Factor	PD	1.5 12	W mW/°C
Power Dissipation (Note 7) Linear Derating Factor	PD	2.1 16.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	83	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R <sub>0JA</sub>	60	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R <sub>θJL</sub>	3.23	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

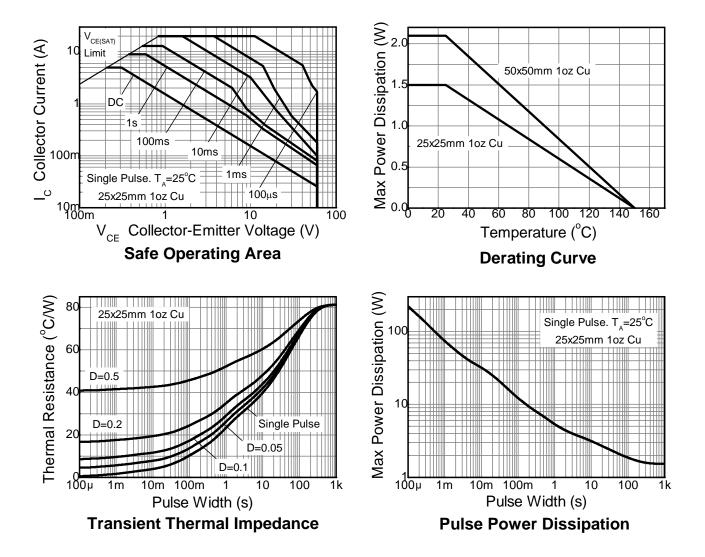
### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

6. For a device mounted with the exposed collector pad on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as note (6), except the device is mounted on 50mm x 50mm 1oz copper.
8. Thermal resistance from junction to solder-point (on the exposed collector pad).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



## **Thermal Characteristics and Derating Information**





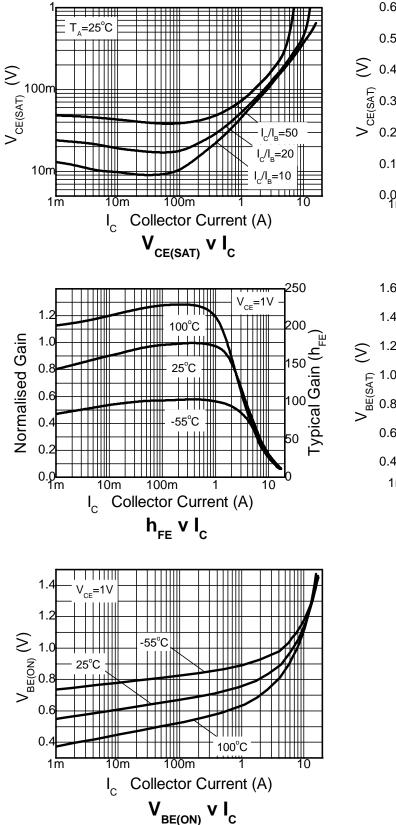
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

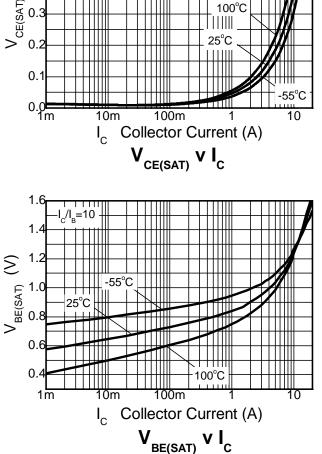
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	190	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CER</sub>	150	190	—	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	60	80	—	V	$I_{C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	—	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CBO</sub>	_	< 1	50 500	nA nA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector Cutoff Current	I <sub>CER</sub> R ≤ 1kΩ	_	< 1	100 500	nA nA	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	< 1	10	nA	$V_{EB} = 6V$
		100	200	—		$I_{C} = 10 \text{mA}, V_{CE} = 1 \text{V}$
DC Current Transfer Static Ratio (Note 10)	h <sub>FE</sub>	100	200	300	_	$I_C = 2A, V_{CE} = 1V$
		55	105	—		$I_{C} = 5A, V_{CE} = 1V$
		20	40	—		$I_{C} = 10A, V_{CE} = 1V$
	Vce(sat)		17	30	mV	$I_{C} = 100 \text{mA}, I_{B} = 5 \text{mA}$
		_	35	55		$I_{C} = 1A, I_{B} = 100mA$
Collector-Emitter Saturation Voltage (Note 10)		_	40	65		$I_{C} = 1A, I_{B} = 50mA$
			90	125		$I_{C} = 2A, I_{B} = 50mA$
			170	230		$I_{C} = 6A, I_{B} = 300mA$
Base-Emitter Saturation Voltage (Note 10)	VBE(SAT)		970	1100	mV	$I_C = 6A, I_B = 300mA$
Base-Emitter Turn-on Voltage (Note 10)	V <sub>BE(ON)</sub>		910	1050	mV	$I_{C} = 6A, V_{CE} = 1V$
Transitional Frequency	f <sub>T</sub>	_	130		MHz	$\label{eq:lc} \begin{array}{l} I_C = 100 \text{mA}, \ V_{CE} = 10 \text{V}, \\ f = 50 \text{MHz} \end{array}$
Output Capacitance	C <sub>OBO</sub>		31		pF	$V_{CB} = 10V$ , f = 1MHz,
Switching Time	t <sub>ON</sub>		42		ns	$V_{CC} = 10V, I_{C} = 1A$
	t <sub>OFF</sub>	_	760		113	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





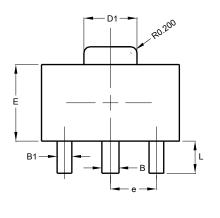
 $I_{c}/I_{B} = 10$ 

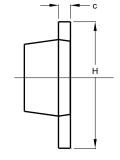


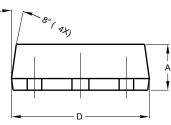
### **Package Outline Dimensions**

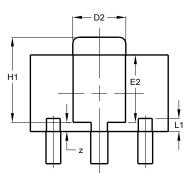
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







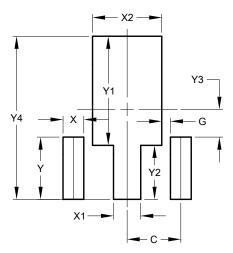


	SOT89					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	1	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	All Dimensions in mm					

### Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT89



Dimensions	Value (in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Y	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2018, Diodes Incorporated

www.diodes.com

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Diodes Incorporated manufacturer:

Other Similar products are found below :

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 2N2369ADCSM 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E US6T6TR 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E UMX21NTR EMT2T2R MCH6102-TL-E FP204-TL-E NJL0302DG 2N3583 2N3879 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E 30A02MH-TL-E NSV40301MZ4T1G NTE13 NTE15 NTE16001 NTE16006 NTE26 NTE320